

Replacing the Metal Electrodes in Triboelectric Nanogenerators: High-Performance Laser-Induced Graphene Electrodes

Pengfei Zhao,^{1,‡} Gourav Bhattacharya,^{2,‡} Sam J. Fishlock,^{2,‡} Joseph G. M. Guy,³ Amit Kumar,³ Christos Tsonos,⁴ Zidong Yu,¹ Shasidran Raj,² James A. McLaughlin,² Jikui Luo⁵ and Navneet Soin^{2,*}

¹Institute for Materials Research and Innovation (IMRI), School of Engineering, University of Bolton, Bolton BL3 5AB, United Kingdom

²School of Engineering, Ulster University, Newtownabbey, Belfast BT37 0QB, Northern Ireland, United Kingdom

³School of Mathematics and Physics, Queen's University Belfast, University Road, Belfast BT7 1NN, Northern Ireland, United Kingdom

⁴Department of Physics, University of Thessaly, 3rd Old National Road, Lamia-Athens, 35100 Lamia, Greece

⁵College of Information Science and Electronic Engineering, Zhejiang University, 38 Zheda Road, Hangzhou 310027, P. R. China

[‡]*Equal Contribution*

*Corresponding author email: n.soin@ulster.ac.uk

Abstract

While significant work is being carried out to develop materials for enabling high surface charge density triboelectric nanogenerators (TENG), little attention has been paid to the role of electrodes responsible for charge collection. This work reports on the facile synthesis and use of high crystallinity, sp^2 -hybridised laser-induced graphene (LIG) as a high-efficiency electrode for triboelectric nanogenerators (TENGs). Using a conventional 10.6 μm CO_2 laser, the controlled, direct photothermal conversion of dielectric, tribo-negative polyimide (PI) and tribo-positive cellulosic paper into corresponding PI-LIG and paper-LIG, respectively, facilitates a significantly higher electrical output as compared to the commonly utilised adhesive aluminium electrodes. The LIG based paper-PI TENGs showed significantly higher electrical output characteristics with a peak-to-peak voltage of up to ~ 625 V, a current density of ~ 20 $\text{mA}\cdot\text{m}^{-2}$ and a transferred charge density of ~ 138 $\mu\text{C}\cdot\text{m}^{-2}$ with a maximum power output of ~ 2.25 $\text{W}\cdot\text{m}^{-2}$, respectively, while the corresponding values for the conventional Al-tape electrode-based paper-PI TENGs were 400 $\text{V}_{\text{p-p}}$, ~ 10 $\text{mA}\cdot\text{m}^{-2}$, ~ 85 $\mu\text{C}\cdot\text{m}^{-2}$ and 0.9 $\text{W}\cdot\text{m}^{-2}$, respectively. The mechanically robust LIG electrodes show excellent stability with less than 5.0% variation in output over 12,000 contact cycles. Using Kelvin probe force microscopy (KPFM) measurements, we have measured differences in not only the average surface potentials of the triboelectric surfaces (-0.26 V for pristine PI vs. $+0.34$ V for paper, which drive the TENG electrical output) but also for the LIG's synthesised from them (-0.08 V for PI-LIG vs. $+0.26$ V for paper-LIG), suggestive of the role of initial surface chemistry in the formation of LIGs. The enhanced (~ 150 %) power density for LIG based TENGs is ascribed to the lowering of the charge transfer barrier height *via* the alignment of Fermi levels resulting in higher surface charge on the dielectric surface and the significantly (~ 6 orders) lower interfacial contact impedance of LIG as compared to adhesive aluminium electrodes. Thus, *via* the removal of the additional interface between the triboelectric surface and electrode, high-performance metal-free TENGs with excellent prospects for enabling energy harvesting applications can be realised.

Keywords: Laser-induced graphene; triboelectric nanogenerators; surface potential; energy harvesting; interfacial resistance

1. Introduction

Portable, wearable- electronic devices and technologies are fast becoming an indispensable part of our daily lives. These technologies are largely driven by the need of ubiquitous connectivity – known as IoT (Internet of Things) and are enabled by devices performing functions of health monitoring, environmental sensing, data sharing/processing by integrating multiple technologies, including sensors, real-time analytics, machine learning and embedded systems etc., for realising human-to-human or human-to-network interaction [1,2]. However, the limitations of the battery capacity have forced both the device and product designers to trade-off functionality and endurance for product size. The past few years have seen a rapid development in the field of energy harvesting, especially triboelectric effect based nanogenerators which show the potential of enabling self-powered systems [3,4]. As a type of mechanical energy harvester, the simplest of triboelectric nanogenerators (TEENG) can be assembled using commodity polymer materials and simple fabrication techniques. As compared to the other energy harvesting devices, the TEENGs have been shown to work more efficiently at low-frequencies (1-10 Hz) and exhibit conversion efficiency of up to 85% [5]. As a result, since their invention in 2012, TEENGs based on a combination of contact electrification and electrostatic induction effects are now regarded as one of the most effective means to harvest mechanical energy [4-7]. For the commonly reported vertical contact-separation mode TEENG, two layers of tribo-charge with opposite polarity are formed on the interface *via* the contact of two dielectric materials with opposite triboelectric tendencies. The subsequent vertical periodic change of the distance between two materials causes a varying electric field which induces a periodic electric potential on the back-metal electrodes[8].

While the interfacial dielectric materials which directly participate in the tribo-charge generation (contact electrification) process are considered to be the most important component of TEENGs, the material properties of the back electrodes are equally important affecting the output behaviour of the TEENG. Till date, many conductive materials have been applied as the back electrodes, including gold [9,10], aluminium [11,12], copper [13] and carbon [14] etc. For designing TEENG systems which can harvest energy from non-conformal surfaces, thin metal films show poor behaviour due to their unsuitable elastic behaviour (high Young's modulus) as compared to the triboelectric polymer surfaces. Moreover, the coating or adhesive process can affect the durability and life-time of the devices owing to the poor bonding of the metal electrode to the soft polymer contact layers [15]. These issues are fundamentally applicable to nearly all metallic thin films and may be difficult to overcome [16]. Invariably, the poorly

adhering electrodes result in a reduced electrical output as the charge collectors are not able to fully capture the generated charge [16]. As such, liquid metal (room temperature liquid) e.g. Galinstan based electrodes owing to their conductive, fluidic and highly conformal nature have been explored as charge collecting electrodes in TENGs [17]. However, when exposed to air, Galinstan oxidises readily, is difficult to handle and has only been shown to work in single-electrode TENGs, which fundamentally has much lower electrical output than the vertical-contact mode TENGs [17]. Amongst all the reported electrodes, carbon-based electrodes are considered as an ideal option for realising effective electrical properties with high flexibility and examples of TENGs utilising multi-walled carbon nanotubes mesh [16] and graphene [18] have been reported. In a recent work, we have shown the use of conductive carbon tape electrodes with coarse surface and high electronic affinity as a way to boost the electrical performance of TENGs, which was ascribed to a high density of pores between the triboelectric polydimethylsiloxane (PDMS) layer and the underlying carbon electrode [14]. As such the direct synthesis of micro-structured conductive sp^2 -carbon on the polymeric contact layer to create back electrode is thus an ideal option for realising high flexibility and a thorough, intimate electrical connection of the layers.

Schumann et al. in 1990 reported that KrF ultraviolet laser irradiation could convert polyimide (PI/Kapton) and polybenzimidazole into glassy carbon with permanently enhanced electrical conductivity [19]. In 2014, Lin et al. too demonstrated successful photothermal conversion of PI containing sp^3 -carbon atoms into three-dimensional networks which consist of sp^2 -carbon atoms and exhibited high electrical conductivity and flexibility. The film synthesised through this route is called as laser-induced graphene (LIG) [20]. Subsequently, Chyan et al. demonstrated that a wide range of carbohydrate-containing substrates (*i.e.* cellulose and lignin) could also be converted into LIG through a multiple pulsed laser scribing technique without losing the conductivity and the processing efficiency [21].

Stanford et al. have recently introduced the ambient CO_2 laser ablation technique to develop LIG electrodes for TENG devices [22]. Using a combination of PI and polyurethane tribo-surfaces with LIG back-electrodes, these dielectric-dielectric TENGs were shown to provide a ~ 1 kV voltage output, however, the overall power density was limited to ~ 0.76 W.m⁻² [22]. More recently, Jiang et al. have reported a porous MXene-PDMS composite film as a tribo-layer which was then adhered to a PI-LIG electrode film [23]. Despite the performance-enhancing porous microstructure of the composite films, the addition of the extra interface between the tribo-layer and PI-LIG electrode led to a relatively poor power output of 0.6 W.m⁻²

² [23]. While these studies successfully introduced novel electrodes materials to overcome the cost and throughput constraints of vacuum deposition and chemical vapour growth techniques, they were fairly limited in their scope. Primarily focusing on the LIG's properties of high flexibility and conductivity; only the basic electrical output of LIG-based TENGs and their potential use in driving portable electronic devices were discussed [22-24]. Devoid of a systematic comparison between the conventional continuous metal film electrodes and porous micro-structured LIG electrodes, the works provided no discussion of the underlying physical mechanisms, interfacial properties, or the interplay of surface chemistry and surface potential which drives the LIG-based TENG's output performance [22-24]. From a testing perspective, the unavailability of key output parameters of surface charge density and transferred energy per cycle, alongside, the lack of long-term stability measurements meant that no comparison on the efficacy of LIG based TENGs could be carried out.

Thus, in the existing literature for a complex system such as the LIG-based TENGs, we note that the physical understanding for their purported performance is missing. This is primarily owing to a lack of understanding of (i) the nature of the electrical interface between the laser metal/dielectric surfaces and (ii) correlation between a precursor's surface chemistry and its subsequent post-laser-irradiation (LIG) surface potential, which could lead to interfacial charge transfer *via* alignment of energy levels. This interface is especially important for surface charge driven processes as its modulation can lead to a variation in the metal-dielectric potential barrier and thereby the subsequent charge density. These significant knowledge gaps, which could present a serious impediment to the future applications of LIG-based TENGs, have been addressed for the first time by the work we present in this publication. The work will help to provide a new knowledge base to allow for the further practical exploitation of LIG and other related electrode systems.

Herein, we report on the use of laser-induced graphene (LIG) synthesised directly on tribo-negative polyimide (PI), and tribo-positive cellulose-based paper surfaces to fabricate high-performance TENGs. The highly crystalline sp² LIG electrodes are flexible, robust, and **can** provide much higher outputs owing to the much more intimate contact to the dielectric layers. The fabricated **LIG-based TENGs** shows a peak-to-peak voltage of up to ~625 V, a short-circuit current density of ~25 mA.m⁻² (corresponding a charge density of ~138 μC.m⁻²), and energy pulse of ~11.8 μJ.cycle⁻¹ with an instantaneous power density of 2.25 W.m⁻², at a matched 100 MΩ load, respectively. All these values are significantly higher than the values

for conventional aluminium electrode-based PI/paper TENGs. The LIG electrodes are mechanically stable and the developed TENG shows excellent stability with less than $\pm 7\%$ variation in its electrical output over 12,000 contact cycles. In-depth characterization of the LIG electrodes shows clearly the role of initial surface chemistry in the formation of subsequent LIGs wherein an average surface potential values of -0.08 V for PI-LIG (*vs.* -0.26 V for pristine PI), and $+0.26\text{ V}$ for paper-LIG (*vs.* $+0.34\text{ V}$ for paper) was observed, which then is reflected in the work function differences and the subsequent variation of the barrier. Furthermore, using dielectric relaxation spectroscopy, we have thoroughly studied the interface between the dielectric and electrode to gain insight into the reasons for the enhanced performance of the LIG electrodes. **We further show the use of a fast-charging fly buck circuit for enhanced conversion/storage efficiency to demonstrate metal-free TENG systems that can provide sufficient energy to continuously power an electronic device. The work will help to provide a new knowledge base to allow for the further practical exploitation of LIG and other related electrode systems.**

2. Experimental

2.1 Materials and characterization

Commercially obtained Polyimide (PI, 125- μm thick PI, Kaneka, Apical NP, USA) and Whatman filter paper No. 1, were lased using a 10.6 μm wavelength CO_2 laser cutter (Universal Laser 230 VLS) under ambient conditions (Fig. 1 (a, b)). For the PI-LIG samples, the laser power was kept at 8.1 W (32.5 % of 25 W laser rating) with a scan speed of 570 $\text{mm}\cdot\text{s}^{-1}$. The PI-LIG electrode was designed using AutoCAD (Autodesk, 2017 USA) software and patterned as a $25 \times 40\text{ mm}^2$ block in raster mode at 1000 PPI (25.4 μm separations between pulses). To produce paper-LIG, fire-retardant pre-treatment is necessary to avoid its decomposition to volatile compounds during the laser treatment [21]. For this, the paper substrate was treated using a commercial flame retardant (Firechief, UK). The lasing procedure was similar to that used for PI-LIG, except we lased the surface twice to obtain a high-quality paper-LIG electrode [21]. During the initial lasing run, the paper substrate was 0.8 mm out of focus (*i.e.* the laser focal point was 0.8 mm above the **paper surface**), **followed by in-focus laser treatment. To synthesise paper-LIG, power for both the laser-runs** was kept at 1.5 W with a scan speed of 150 $\text{mm}\cdot\text{s}^{-1}$.

A Hitachi SU5000 field emission scanning electron microscope (SEM) was used to study the surface morphology and cross-section of the LIG layer on PI and paper substrates. X-ray photoelectron spectroscopy (XPS) was performed on a Thermo Fisher Scientific NEXSA spectrometer using a micro-focused monochromatic Al X-ray source (19.2 W) over an area of approximately 100 microns. Data were recorded at pass energies of 150 eV for survey scans and 40 eV for high-resolution scans with 1 eV and 0.1 eV step sizes, respectively. Charge neutralization of the sample was achieved using a combination of both Ar⁺ ions and low energy electrons. The Raman spectra were recorded using a Renishaw Raman spectrometer (inVia) with a 532 nm Laser source at a nominal power of 25 mW for 60 s at 50× magnification. Nanoscale surface potential mapping was undertaken using an Asylum Research MFP-Infinity atomic force microscope in the KPFM mode, which allows measurement of true surface potential through operation in a two-pass mode. For these KPFM measurements, Pt-coated Si tips (Nanosensors PPP-EFM) with stiffness constant of 2.8 N.m⁻¹ were used.

2.2 Preparation and electrical characterization of TENGs

To prepare the conventional TENG control samples comprising of PI and paper dielectric layers, conductive aluminium tapes (50 μm thick) as electrodes were attached to two separate glass slides (2 cm × 2 cm × 0.1 cm). The LIG electrode-based TENG was produced by directly attaching the PI- or paper-LIG films to two glass substrates, with the LIG surfaces in contact with the glass while the PI- and paper- surfaces opposite to each other, as the tribo-negative and positive layers, respectively (see Fig. 1(h, i)).

A computer-programmable dynamic linear motor system (Linmot) combined with a force sensor (JHBM-H1) was used to simulate constant periodic mechanical input of the TENGs by controlling the contact force (10-50 N), frequency (1-9 Hz) at a fixed spacer distance (5 mm) of the two tribo-contact layers. An oscilloscope (Tektronix MDO3022 connected via a 100 MΩ input impedance high accuracy, high voltage passive probe) and a picoammeter (Keysight B2981A) were connected in parallel or serial, respectively, to measure the output voltage and the short-circuit current data which was then further utilised to calculate the output current density and charge density. For all the TENG electrical measurements on picoammeter and oscilloscope, the electrodes corresponding to the paper (tribo-positive) side were connected to the positive lead, while the PI (tribo-negative) side electrodes were grounded.

3. Results and discussion

3.1 Material characterization

After the lasing process, a clear visual difference between the pristine and lased surfaces can be clearly observed, corresponding to the laser-induced pyrolysis/carbonisation. For both paper and PI substrates, it was observed that an optimal laser irradiation led to the formation of carbon-based material protruding from the starting substrate (Fig. 1(c, d)). In fact, the morphologies for both the PI-LIG and paper-LIG surfaces showed a loosely packed porous graphitic microstructure (Fig. 1(c, d)), similar to what has been reported by various groups including ours [21, 22, 25]. The uniform cross-sectional thickness of the PI substrate allowed clear visualisation of the interface between the pristine PI and PI-LIG (Fig. 1(c)). Based on our experimental conditions, it was observed that $\sim 30\ \mu\text{m}$ of the PI substrate was ablated and converted into LIG while the opposite face of the PI substrate remained intact with no visible damage, owing to the limited laser penetration depth and thermal properties of Kapton [26]. In the case of the paper substrate, owing to its fibrous nature (see Fig. S1, supporting information, for SEM image of the pristine paper surface), the cross-sectional and interfacial measurements were difficult (Fig. 1(d)); however, the surface morphology of both the paper-LIG and PI-LIG appeared similar (Fig. 1(e, f)). For the process of the direct laser writing on PI substrates, Luo et al. have reported that the porous nature of the LIG films arises due to the “bombing” effect which leads to the release of CO_2 , H_2O , H_2 and CO and other pyrolysis gases leading to an increased height of the synthesised LIG layer [27]. This hypothesis is supported by the earlier studies of Inagaki et al., wherein a two-step process of carbonisation of polyimides was observed [28]. The first-step, occurring between $500\text{--}650\ \text{°C}$ proceeds *via* the breakage of the carbonyl groups in the imide part which leads to an abrupt release of CO and CO_2 , while the second-step (occurring in the range $800\text{--}1000\ \text{°C}$), leads to the release of H_2 , O_2 and N_2 accompanied by graphitisation [28, 29]. This pyrolysis/carbonisation process proceeds at a very fast rate owing to the rapid laser heating, which is a characteristic of the laser-writing process [30]. It should, however, be noted that for both the cases, the unexposed side of the PI and paper substrates was not affected by the laser irradiation and could, therefore, be used directly as the triboelectric contact surface.

The Raman spectroscopy of both PI-LIG and paper-LIG samples was carried out to ascertain the nature and quality of the graphitic films. The presence of defective graphitic carbon was confirmed with a broad D band at $\sim 1350\ \text{cm}^{-1}$, G band at $\sim 1580\ \text{cm}^{-1}$ and the 2D band at ~ 2700

cm^{-1} for both the samples, albeit with varying full width at half maxima (FWHM) values (see Fig. 1(g)) [31]. A simple comparison of the PI and paper-derived LIG shows that the I_D/I_G ratio for the PI-LIG was marginally higher (0.82) as compared to the paper-LIG (0.79) and can be attributed to the differences in the chemical bonding. The thermally stable polyimides contain aromatic backbone structures composed primarily of fused rings and rings directly linked by carbon-carbon bonds whereas the paper contains largely aliphatic carbon in the form of cellulose (see XPS discussion) [32]. It has been shown previously that aliphatic **carbons can readily decompose** and produce more defects on laser irradiation, and hence the observed differences in the I_D/I_G ratio can be easily understood [32, 33]. In the second-order Raman spectra, the FWHM of the fitted 2D peak for PI-LIG is slightly higher (83 cm^{-1}) than that of the paper-LIG (72 cm^{-1}) which is typical for 3D graphitic films consisting of randomly stacked graphene layers along the dominant c-axis [20]. Concurrently, the I_{2D}/I_G value of approx. 0.68 for PI-LIG and 0.55 for paper-LIG, respectively, further confirms the excellent graphitisation [20, 32-34].

To understand the compositional changes occurring upon the laser irradiation, XPS analysis of the pristine PI, paper and their corresponding derived LIGs has been carried out (Fig. 2). For the pristine PI films, the surface chemical composition was measured to be C (78.05 at%), O (17.30 at%) and N (4.65 at%) which matches well with the theoretical and reported values [34, 35]. The high-resolution C 1s spectra for the pristine PI (Fig. 2(a), left panel) was deconvoluted into four main functional groups: carbon in aromatic rings (C-C) not attached to the imide ring (284.6 eV), carbon atoms bonded to nitrogen (C-N) at 285.6 eV, carbon atoms single-bonded to oxygen (C-O) at 286.4 eV and carbonyl groups (C=O) present at 288.7 eV, respectively. For the PI core-level O 1s spectra (Fig. 2(b)), two components corresponding to the C=O and C-O bonding were observed at ~ 532.1 and 533.4 eV, respectively [36]. A symmetrical peak arising from the C-N bonding at ~ 400.6 eV was observed for the N 1s core-level region (inset Fig. 2(b)) [35, 36]. After the laser ablation process to **obtain** PI-LIG, significant changes in the core-level spectra were observed with the components at 285.6 eV (C-N), 286.4 eV (C-O) and 288.7 eV (C=O) **being reduced** significantly, while the components at ~ 285.0 eV, corresponding to C-C and C=C bonding **show a dramatic increase** (Fig. 2(a), right panel and Fig. 2(c)). Correspondingly, the surface composition of the PI-LIG changed dramatically, wherein, most of the surface oxygen/nitrogen was removed (C (92.57 at%), O (6.53 at%) and N (0.90 at%)), with the corresponding C/O and C/N atomic ratios changing from 4.5:1 and 16.8:1 (for pristine PI) to 14.2:1 and 102:1, respectively (inset Fig. 2(a)). These compositional

values support the earlier discussion and confirm that the CO₂ laser irradiation of PI films releases both oxygen and nitrogen, amongst other pyrolysis gases, as volatile species and the residual films are largely sp² carbons only [28, 29, 35, 36].

Similarly, for the paper substrate, while the initial surface chemistry is dominated by C (55.02 at.%) and O (41.80 at.%), trace values of S (1.68 at.%) and N (1.50 at.%) were also detected (Fig. 2(d), left panel) [37]. After the CO₂ lasing process, the paper-LIG surface composition was predominantly C (72.79 at.%) and O (20.02 at.%) with some trace quantities of B (3.79 at.%), S (2.53 at.%) and N (0.88 at.%), see Fig. 2(d) right panel and Fig. 2(f). The presence of Boron is ascribed to the fire-retardant spray, which was sprayed onto the paper substrates [21, 33]. As discussed earlier, for cellulosic materials, the fire-retardant pre-treatment is necessary to avoid their decomposition to volatile compounds during the laser treatment [21, 33]. The significant difference in the residual oxygen content of the paper-LIG can be ascribed to the effects of the physio-chemical structure (randomly laid fibrous (cellulose) and non-fibrous (fillers) materials) of the paper as well as the presence of the fire-retardant in the matrix which reduces ablation. As cellulose and hemicellulose are prone to burning at relatively low temperatures, the borylation of the paper substrate helps catalyse dehydration and oxygen-elimination reactions of cellulose, resulting in an amorphous char high in aromatic content which is then converted to paper-LIG. **During the** lasing process, the corresponding C/O and **C/N atomic ratios changed from** 1.32:1 and 36.68:1 (for pristine paper) to 3.63:1 and 82.71:1, respectively [21, 33, 37] (see inset Fig. 2(d)). It should be noted that these results are very similar to those reported by Lee et al. in their recent work on **the** laser-induced graphitisation of cellulose substrates [37]. This significant difference in the surface chemistry of the LIG films is also reflected in their respective surface contact potentials and is discussed in the later section.

3.2 Electrical characterization of TENGs

To assess the suitability of the LIG as charge collection electrode, we have undertaken comparative studies of the following TENG configurations: pristine PI (tribo-negative) vs. pristine paper (tribo-positive) with Al back electrodes (control) and PI vs. paper with LIG electrodes (see Fig. 1(g, h)). The measured electrical output performance of the PI/paper-based TENG with Al and LIG electrodes is shown in Fig. 3. It is understood that under compressive force when the triboelectric surface such as paper/PI surfaces are in contact, equal and opposite triboelectric charges, *i.e.* negative charges on the PI and positive charges on the paper are generated [11, 12, 38]. Upon the removal of the force, the presence of these opposite charges

on the surfaces leads to the formation of **electric potential** between the two metal electrodes, which can drive the electrons through an external circuit until the potential difference is neutralized. As can be observed, within the range of the measured contact forces, both the Al (Fig. 3(a)) and LIG (Fig. 3(c)) electrode-based **TENGs exhibit a linear relationship between** the voltage output and the contact force. While the peak-to-peak voltage, V_{p-p} , of the Al electrode-based TENG (Fig. 3(a)), showed a relatively small increase in the voltage outputs ranging from $\sim 260 V_{p-p}$ (at 10 N) to $\sim 400 V_{p-p}$ (at 50 N), the LIG based TENG (Fig. 3(c)) showed consistently higher values ranging from $\sim 360 V_{p-p}$ at the minimum contact force of 10 N to $\sim 635 V_{p-p}$ (at 50 N), respectively. Correspondingly, the Al electrode-based TENG (Fig. 3(b)) was only able to provide a maximum current density and transferred charge density values (at 50 N) of $\sim 10 \text{ mA}\cdot\text{m}^{-2}$ and $\sim 85 \mu\text{C}\cdot\text{m}^{-2}$, respectively. Comparatively, the LIG based TENG **showed a higher short-circuit current density** and effective charge density value of $\sim 20 \text{ mA}\cdot\text{m}^{-2}$ and $138 \mu\text{C}\cdot\text{m}^{-2}$, respectively (Fig. 3(d)). According to literature and indeed our previous reports, the impact force and impact frequency are the two most important operating parameters which control the electrical output of the TENGs [11, 12, 38-40]. For both the LIG and Al-based PI-paper TENGs, an increase in the charge density values and the voltage/current peak values across the force range was observed which arises from the growth of the transferred charge amount induced by higher surface tribo-charge density. **This increase of the generated tribo-charge density with the increasing force** can be attributed to the combined effect of the mechanical stress-induced higher contact area, and the mechanochemical phenomenon as the localised stress which is further magnified by the roughness of the paper substrate [11, 12, 38-40]. As the LIG based **TENGs produced significantly** higher electrical output, further measurements of the frequency dependence were limited to these LIG PI-paper TENGs only.

As shown in Fig. 3(e), by varying the contact frequency (1-9 Hz), the magnitude of the LIG based PI-paper TENG output voltage peak dramatically enhanced from ~ 300 to $\sim 625 V_{p-p}$, **while**, the peak short-circuit charge density increased from $\sim 3.6 \text{ mA}\cdot\text{m}^{-2}$ to $\sim 22.0 \text{ mA}\cdot\text{m}^{-2}$, respectively. **However, contrary to the phenomenon observed from force-output results; with an increase in the operating frequency, the most crucial output parameter of transferred charge density gradually decayed from $\sim 207 \mu\text{C}\cdot\text{m}^{-2}$ to $\sim 113 \mu\text{C}\cdot\text{m}^{-2}$, which contradicts the growth trends of the output voltage and current.** This behaviour is different from the normally observed behaviour in TENGs, wherein the charge density and current density have a direct relationship [38-40]. It is understood that for the contact-mode TENGs, the output current is influenced by the interaction between the triboelectric layers, *i.e.* the instantaneous current during **the release**

cycle is strongly affected by the separation speed, see Eq. 1 below [38-40, 41]. Under the short-circuit conditions, the transferred charge for contact-separation mode TENGs is represented by the following relationship:

$$Q_{sc} = \frac{S\sigma x(t)}{d_0 + x(t)} \quad (1)$$

Where S is the plane contact area, σ is the surface electrification charge density, $x(t)$ is the real-time distance between two contact layers, and d_0 is the effective thickness represented by:

$$d_0 = \frac{d_1}{\varepsilon_1} + \frac{d_2}{\varepsilon_2} \quad (2)$$

Where ε_1 and ε_2 represent the relative dielectric constants of the two contact triboelectric contact layers of thicknesses d_1 and d_2 , respectively [41].

The singular waveform of the current outputs obtained at different operation frequencies is shown in Fig. S2 (supplementary information), where it can be seen that a lower operating frequency allows a longer charge transfer time between the two electrodes and therefore, a higher amount of charge (derived by integrating the area under the singular cycle pulse of the current density) can be expected. As can be observed in Fig. S2, even though the peak current density is increasing, the current pulse width is getting narrower with the increasing frequency owing to a significantly shorter contact time between the two triboelectric interfaces [39]. A higher operation frequency results in a sharper and higher output peak, which can be useful for applications which require a high voltage/signal amplitude, *i.e.* as a power supply of an electrospinning system, plasma stimulation or excitation signal of an RF (Radiofrequency) wireless communication system [42]. Moreover, unlike the common TENG systems such as PA-6/PTFE [11, 12], PEO/PTFE or PDMS/PEO [40] where the effective stiction between the two “soft-polymers” is high leading to a relatively constant release time between the triboelectric surfaces; the relative lack of stiction between the PI and paper surfaces also contributes to the observed variation in the growth trend of current and transferred charge density.

The output power of both the Al and LIG based PI-paper TENGs was tested by connecting various electrical loads in series at a constant operating condition of 50 N force, 5 mm spacer distance and 5 Hz working frequency. The maximum output power of the LIG or Al electrode-based TENGs at impedance matching condition was measured by connecting in series various external load resistors. The accurate instantaneous peak power values can thus be measured by

measuring the current across the resistor via the following equation:

$$P = I_{peak}^2 R \quad (3)$$

where I_{peak} stands for the maximum current value measured current across the load resistance, R . It can be observed in Fig. 4(a), that the maximum output power of both Al and LIG based TENG devices was obtained at a load resistance of $\sim 100 \text{ M}\Omega$. At the impedance matching conditions, the LIG electrode-based TENG can output a power density of nearly $\sim 2.25 \text{ W}\cdot\text{m}^{-2}$, which more than 2.5 times higher than the Al electrode-based one ($\sim 0.9 \text{ W}\cdot\text{m}^{-2}$). It should be noted that this reported power of the **PI-paper LIG TENG is nearly 3 times higher than the value reported ($0.76 \text{ W}\cdot\text{m}^{-2}$) by Stanford et al. [22] and Luo et al. ($0.8 \text{ W}\cdot\text{m}^{-2}$) [24], and nearly 4 times higher than the value reported by Jiang et al. ($0.6 \text{ W}\cdot\text{m}^{-2}$) [23] for LIG based dielectric-dielectric TENGs**. As illustrated in the frequency-output characterisation section, it has been demonstrated that the magnitude of the instantaneous output peaks mainly depends on the duration of the charge transfer time instead of the amount of charge transferred. Therefore, for energy harvesting/conversion purpose, the energy (E) derived from the area under the power curve of each operation cycle at the impedance matching condition is much more representative of the output electric energy characterization. This energy, E , is given by:

$$E = \int_{nt}^{(n+1)t} I_t^2 R_{load} dt \quad (4)$$

where I denotes the measured current values across the impedance-matching load resistance, n is the number of generation cycle, and t is the time period of each energy generation cycle (0.2 s at 5 Hz working frequency) [39]. At the impedance matching condition (when $R_{Load}=100 \text{ M}\Omega$), the harvested energy was calculated to be $\sim 11.8 \mu\text{J}\cdot\text{cycle}^{-1}$ (Fig. 4(b)), which is twice the harvested energy from an Al electrode-based one ($\sim 5.5 \mu\text{J}\cdot\text{cycle}^{-1}$) and similar to the energy harvested from a PA6/electrospun-PTFE based TENG reported in our earlier work ($\sim 13.8 \mu\text{J}\cdot\text{cycle}^{-1}$) [12].

The output stability of the LIG based TENGs was further demonstrated by monitoring the **output variation over a long-period operation of more than 12,000 energy generation cycles at 50 N, 5 Hz conditions**. As shown in Fig. 4(c, d), both the voltage and current outputs initially gradually dropped down by $\sim 5\text{-}7 \%$ in the initial 900 s operation time; however, no further attenuation was observed afterwards. The continuous stable output demonstrates not only the duration of the tribo-charge on the selected dielectric material surfaces but also the sufficient mechanical strength of the underlying LIG electrode layer. It is worth mentioning that all the

previous electrical characterisations were measured after a period of pre-operation time during which the output was allowed to stabilise. We have further utilised this metal-free PI-Paper LIG based TENG to power up an electronic calculator using our previously developed fly-buck converter circuit (Fig. 4(e, f)) [40]. The fly-buck circuit composed of a DB107S rectifier bridge, a BSS127 MOSFET transistor; a COTS coupled inductor with a 20:1 turn ratio, a MBRM110L Schottky diode, and a storage capacitor allows enhanced storage rate of the TENG output [40]. The circuit provides two main functionalities: (i) allowing the periodic transmission of the rectified TENG output when the output voltage is maximised at the largest separation distance ($x(t)$) and (ii) managing i.e. step-down the TENG output for storage. As compared to a commonly used full-bridge rectifier circuit, the fly-buck circuit not only provides a higher efficiency as compared to a standard full-wave rectifier but also provides fast-charging capability [40]. Owing to this capability, a $2 \times 2 \text{ cm}^2$ PI-paper LIG TENG working at a frequency of 3 Hz, was able to drive a calculator in real-time, whose coin cell batteries had been removed (See Supplementary video 1). Even after the TENG stopped working, the calculator was able to function for tens of seconds owing to the energy stored in the capacitor (See Supplementary video 2). Thus, the metal-free LIG based TENG devices can provide significant power densities suitable to power up electronic devices and are robust enough to sustain a long-term operation.

3.3 Why do LIG electrode-based TENGs perform better?

To understand the output behaviour of the LIG based TENGs, we have investigated the material chemistry, dielectric relaxation mechanism and measured the average surface potential of the triboelectric surfaces as well as that of the LIG electrodes using KPFM. The KPFM measurements rely on the matching of tip bias V_{DC} with the contact potential difference between the sample and the probe, V_{CPD} , by nullifying the vibration of the probe, which is initially driven by the electrostatic force induced on the AFM probe. It should be noted that the mapped surface potential or the contact potential difference (V_{CPD}) has contributions arising from not only the differences in the work functions but also from the presence of uncompensated charges, particularly for polymeric and non-metallic samples [39]. The average surface potential of pristine PI (Fig. 5(a, b)) was measured to be -0.26 V, while for the paper substrate (Fig. 5(e, f)), the corresponding distribution of the surface potential was much broader with a peak value at around +0.34 V. A higher surface potential implies that the electrons can be easily donated from the surface and the surface will gain a positive charge after contacting other materials [39]. Therefore, as compared to the PI, the paper is triboelectrically positive

and thus has a higher ability to donate electrons. It should be noted that this difference between the surface potentials of the two dielectric surfaces is not as wide as for other classical triboelectric systems such as PTFE/PA-6 [12], PEO/PDMS [40] or the more recently developed AFR/PTFE [39] and is subsequently reflected in the relatively lower output of the paper/PI TENG, thereby demonstrating the need for judicious control of the materials for TENG devices. To further ascertain how the formation of LIG changes the surface potential of the electrodes and if that has a role in the ensuing performance of LIG based TENGs, we have also measured the KPFM response of the paper-LIG and PI-LIG. For comparison, we have also measured the surface potential of standard Al tape electrodes (~ 0.9 V, Fig. 5(i)) which matches well with the value expected due to the differences in the work function of the Pt tip (5.2 eV) and that of Al (4.2 eV).

While it would be expected that the laser ablation of a surface should essentially remove the majority of polymer functional groups and erase the chemical history of the pristine surface, surprisingly, we observed a significant measurable difference between the surface potential of the LIG obtained on the paper and the PI substrates. While the PI-LIG still showed a relatively negative surface potential of -0.082 V (Fig. 5 (c, d)), the paper-LIG showed a value of +0.26 V (Fig. 5 (g, h)), suggesting a significant role of initial surface chemistry in the subsequent formation of LIGs and effects of residual surface chemistry. To understand this difference, we need to revisit the XPS measurements of the surface functional groups present on the LIG surfaces. As compared to the surface composition of PI-LIG ((C (92.57 at%), O (6.53 at%) and N (0.90 at%)), the paper-LIG has much more significant amount of residual oxygen on its surface (C (72.79 at.%) and O (20.02 at.%) and the presence of residual C-O and C=O groups (see Fig. 2(d) right panel and Fig. 2(f)), providing a positive charge onto the surface which is further reflected in its positive surface contact potential [39, 40]. This agrees well with our earlier reports [39, 40] and that of Diaz et al. [43] where it was reported that surfaces with oxygen functional groups develop the highest positive charge next only to nitrogenated groups.

It is understood that when two surfaces come into contact with each other, they will exchange charge as determined by their Fermi level (E_F) and work function (ϕ) differences, where a material with a higher work function will act as an electronegative material and accept electrons from a lower work function electropositive material [41, 44, 45]. It is well established that for contact mode TENGs, a larger difference in the work function values of the two triboelectric contact surfaces drives a higher charge exchange density [45]. As the charges get exchanged, they create an electrostatic potential difference which tends to pull them together, thus creating

a contact potential at the point of contact that counteracts the work function difference [45]. However, in nearly all the studies, the initial charge transfer occurring during the formation of the intimate contact between the metal back electrode, e.g. Al and the dielectric surface is ignored. In this respect, recent work by Xu et al. has reported on the role of **metal work function, E_F , contact potential difference, V_{CPD}** , and the resulting barrier height (W) in controlling the tendency and direction of the contact electrification [46]. Using a classic model of dielectric and metal, the “regulation” *i.e.* **altering of the barrier height** upon contact between a dielectric and metal was discussed elegantly [46].

To gain a better understanding of the role of electrodes, we have carried out TENG electrical output measurements on identical triboelectric materials for various combinations of electrodes *viz.* PI-LIG/PI vs. PI/PI-LIG, Al/PI vs. PI/Al and Al/PI vs. PI/PI-LIG, by using the proposed model by Xu et al. [46]. The idea of using identical triboelectric materials was to exclude the electrical output arising from the contact electrification between the dielectrics of different work functions which can overshadow the electrode effects. Voltage and current output for various electrode combinations are shown in Fig. 6(a, b). While it is expected that for the same tribo-materials, a significant electrical output should not be observed owing to the similar nature of the chemical surfaces, we do observe a significant role of the electrode in these measurements. In the case of LIG electrodes (PI-LIG/PI vs. PI/PI-LIG), negligible electrical output was observed ($<8 V_{p-p}$, $0.2 \mu A$) which can be ascribed to the near matching of the work functions of the PI (5.5 eV) and PI-LIG (5.4 eV), which prevented any significant charge transfer between the PI and PI-LIG (Fig. 6(c)). As a result, the neutral states, E_N , were formed in PI which should be near the E_F of PI-LIG (Fig. 6(c)) and **no significant charge transfer occurs across the interface** [46]. In the case of Al tape electrodes on PI, the work function differences between the dielectric and metal are much more significant (Al 4.2 eV, PI 5.5 eV), which would lead to an alignment of the Fermi levels where electrons would be transferred from Al to PI, endowing the PI surface with a negative charge and leading to the formation of E_N states in PI (Fig. 6(d)) [46]. Considering this TENG configuration, either of the two Al/PI surfaces could potentially have a slightly higher initial negative charge (owing to the local variations in surface chemistry, morphology etc.). Now, when these two surfaces **come into contact with each other**, with the E_N being at similar levels, for the electron transfer to take place, only the barrier W needs to be overcome (Fig. 6(e)). This coupled with the initial surface charge produced during the Fermi level alignment, leads to a higher electrical output than as compared to the PI-LIG/PI vs. PI/PI-LIG TENG [46]. In the case of PI-LIG/PI vs. PI/PI-LIG even though the barrier W

should be quite small, there was no significant initial charge to transfer across it and hence poor output was observed. Finally, in the case of Al/PI vs. PI/PI-LIG TENG, on the Al/PI side the initial contact between the electrode and the dielectric will lead to the production of a significant initial charge owing to the large differences in their work functions (PI surface in contact with Al will develop a negative charge). Whereas on the PI/PI-LIG side, the near matching of the work functions leads to the absence of any significant initial charge. In such a scenario, the Al/PI side can be assumed to act as an overall charge provider (tribo-positive), while the PI/PI-LIG side would be an effective electron acceptor (tribo-negative) system with differences in their subsequent E_N states (Fig. 6(f)). The ensuing contact electrification comprising of such as system (Al/PI) with an initial charge and dielectric with no significant charge (PI/PI-LIG) leads to a lowering of the barrier W by ΔE ($W - \Delta E$) which therefore improves the charge transfer and the overall electrical output of the system [46]. By lowering the barrier *via* direct synthesis of metal-free electrodes on triboelectric surfaces, significantly higher charge density can, therefore, be extracted from the TENGs.

It should be noted that in our earlier work, we have reported on the effect of electrode porosity on the TENG electrical output, wherein a device based on microporous carbon electrode showed significantly higher output than conventional adhesive-metal electrodes [14]. For the PI-LIG and paper-LIG electrodes, due to the observed significant micro-porosity, an enhancement in the electrical output is expected. We have further analysed the dielectric/electrode interface using dielectric relaxation spectroscopy to characterize the resistance arising from the interface. The dependence of the real part, ϵ' , of the dielectric function $\epsilon^* = \epsilon' - j\epsilon''$, on the frequency f , is shown in Fig. 7(a) for Al-adhesive-Al (Al-ADH-Al), pristine PI and Al-Polyimide-LIG (Al-PI-LIG) samples. The ϵ' value of the pristine PI is almost constant across the frequency range and takes a value close to $\epsilon' = 2.2$ [47] but does not show any relaxation events in this frequency range. For the configuration Al-ADH-Al, a high-frequency step is observed (Fig. 7(a)) which is due to the existence of dielectric relaxation, while for the intermediate frequencies, ϵ' is almost constant with a value close to $\epsilon' = 3.4$. A slight increase of ϵ' value at the lower frequencies is observed due to electrodes effect, as the direct current (DC) conductivity dominates at this frequency range and is discussed below. In the Al-PI-LIG system, as shown in Fig. 7(a), a step in ϵ' values is present at lower frequencies which corresponds to a polarization mechanism. A high-frequency step is observed similar to the one observed for the Al-ADH-Al, which arises due to the dielectric relaxation of adhesive. The dependence of the alternating current (AC) conductivity $\sigma' = \epsilon_0 \epsilon'' \omega$ (where $\omega = 2\pi f$,

angular frequency) on frequency f is shown in Fig. 7(b) for the Al-ADH-Al, Pristine PI and Al-PI-LIG samples. A clear low-frequency plateau is observed in Al-ADH-Al, which corresponds to a DC conductivity value of $\sigma_{dc} = 5.2 \times 10^{-13}$ S/cm. The DC conductivity is **also given by the relationship**, $\sigma_{dc} = \varepsilon_o \varepsilon'' \omega_M$, where ω_M corresponds to the peak frequency f_M of conductivity relaxation mechanism in electric modulus M^* representation [48]. As shown in Fig. 7(c), which presents the data of the imaginary part M'' of electric modulus, $M^* = M' + jM''$, the lower frequency relaxation of Al-ADH-Al takes a maximum value at frequency $f_M = 0.27$ Hz. So, according to the previous relation, the DC conductivity of adhesive for the Al-ADH-Al sample is calculated to be $\sigma_{dc} = 5.1 \times 10^{-13}$ S/cm, a value almost identical to that extracted from the low-frequency plateau. This fact indicates that the lower frequency mechanism (Fig. 7(c)) corresponds to the conductivity relaxation mechanism of adhesive of Al tape [49]. Based on the previous analysis, the low-frequency peak in M'' of Al-PI-LIG at 7.5 Hz can, therefore, be related to the DC conductivity relaxation of adhesive of the Al tape. The existence of the previous relaxation also leads to a polarization mechanism in the total structure, which causes the lower frequencies step observed in ε' values (Fig. 7 (a)).

To carry out calculations on the adhesive interface characteristics of Al-PI-LIG, an equivalent circuit of a parallel R - C **element was assumed to describe its dielectric response**, where C is the capacitance and R is the resistance of the adhesive [50]. According to the previous model, the maximum value $M''_{max} = 0.018$, corresponding to the conductivity relaxation mechanism of the adhesive interface in Al-PI-LIG (Fig. 7(c)), is related to the capacitance C via the relation $M''_{max} = C_o / 2C$, where $C_o = 16.8$ pF is the geometrical capacitance of the sample [51]. Based on the previous relationship, a capacitance value of $C = 467$ pF is calculated for the adhesive interface of Al-PI-LIG. On the other hand, the relaxation time, τ , of the R - C equivalent circuit is equal to $\tau = RC$ where $\omega_M \tau = 1$, $\omega_M = 2\pi f_M$ with $f_M = 7.5$ Hz, the frequency corresponding to the maximum value of M'' of the conductivity relaxation mechanism. Taking into account the previous value of capacitance, $C = 467$ pF, a value of $R = 45.5$ M Ω **is extracted corresponding to the resistance of the adhesive interface** in Al-PI-LIG structure.

It should be noted that the interfacial resistance for the PI-LIG interface is expected to be much lower, *i.e.* more conductive than the Al-PI adhesive interface, **owing to the presence of LIG phase**. In Figs. 7 (a-c), no relaxation **event or contribution ascribed to the PI-LIG interface was observed in the frequency range 0.1 Hz -1 MHz**. Therefore, it can be safely assumed that the possible relaxation event associated with the PI-LIG interface could, therefore, occur at a

frequency f_M (maximum value of M'') higher than 10 MHz. On the other hand, typical values characterizing the capacitance of PI-LIG interface, assuming it behaves as a surface layer, are in the range 0.01 nF- 1 nF [52]. Thus, to estimate the upper limit of **PI-LIG interfacial resistance** value, R_{max} , the lower values of frequency $f_M=10$ MHz and capacitance $C=1$ nF were used according to the equivalent circuit of the parallel R-C elements. Then, taking into account the relation of $\omega_M\tau = 1$ and $\tau = RC$, the maximum value of PI-LIG interface ($(R_{max} = 16 \Omega)$) was found to be six orders of magnitude lower than this of Al-PI adhesive interface. Considering all the arguments provided in the previous sections, we attribute the greatly improved (150 %) power output of the TENG based on LIG electrodes to a **combination of mechanisms**, including (i) **the physical microporous structure of the LIG electrode**; (ii) the alteration in Fermi levels caused by the contacting triboelectric surfaces and back electrodes leading to an effective alteration in the initial surface charge of the contacting surfaces, thereby increasing the amount of charge transferred and (iii) a significantly reduced interfacial resistance between the **triboelectric material and contacting electrode which acts to decrease the overall resistance of the structure and thereby increase the power density**. Therefore, by eliminating the resistive interface between the triboelectric surface and the metal back electrode, significantly higher charge density can be extracted from the TENGs.

4. Conclusions

In summary, by using a conventional CO₂ laser, we have synthesised crystalline sp² LIG electrodes directly on the surfaces of tribo-positive and tribo-negative materials to significantly enhance the power output of the metal-free TENGs by 150%. The LIG electrode-based paper-PI TENGs exhibit a peak-to-peak voltage of up to ~625 V, a current density of ~20 mA.m⁻² and a transferred charge density of ~138 $\mu\text{C.m}^{-2}$ with a maximum power output of ~2.25 W.m⁻², as compared to 400 V, ~10 mA.m⁻², ~85 $\mu\text{C.m}^{-2}$ and 0.9W.m⁻² for conventional Al electrode-based paper-PI TENGs, respectively. The enhanced performance of LIG electrode-based paper-PI TENG is ascribed to a **combination of factors including the** formation of intimate electrical contact between the electrode and triboelectric surface thereby excluding any additional high resistance interface (such as adhesive when using aluminium tapes) and the lowering of potential barrier improving the charge transfer. Additionally, we have observed the effects of initial surface chemistry on the surface potential of the subsequent LIG electrodes wherein the tribo-positive surface (+0.34 V for pristine paper) maintained an average positive surface potential (+0.26 V), while the tribo-negative surface (-0.26 V for pristine PI)

maintained its negative surface potential (-0.08 V) even after the CO₂ lasing operation. With the robust and mechanically stable LIG electrode layers, the TENG device displays highly stable output for a long test duration of over 12,000 cycles with less than 5% variation. The stable, continuous outputs are significant enough to **continuously power up simple electronic devices in conjunction with the developed fly-buck circuit**. The work, therefore, provides a facile route to develop flexible, metal-free TENGs and concurrently provides a mechanism to enhance their power density by eliminating the highly resistive interface. When used in conjunction with other optimisation techniques, the principles of direct synthesis of LIG electrodes on triboelectric surfaces can provide a simple, cost-effective route for rapidly expanding the role and uptake of TENG energy harvesters.

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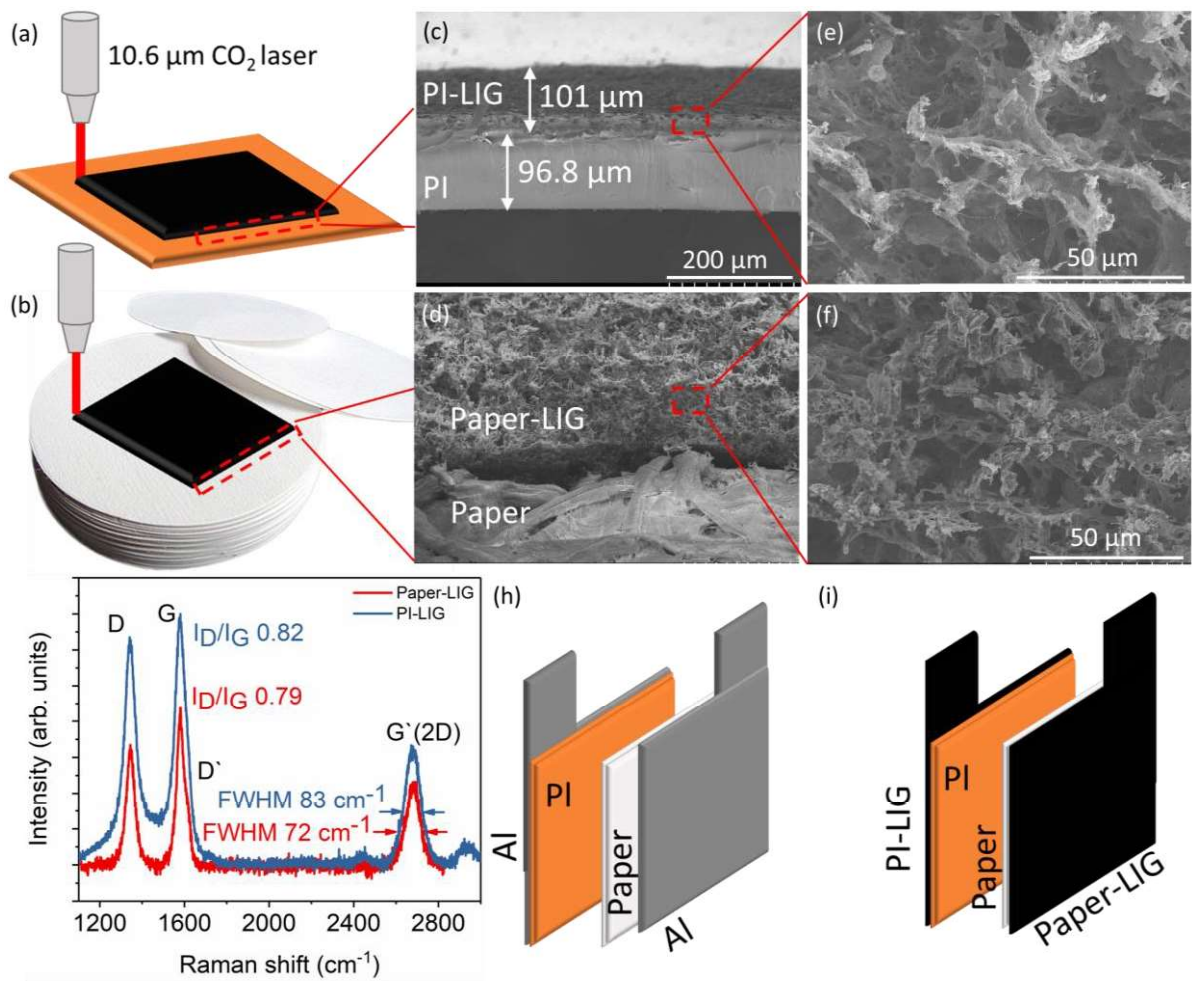


Fig. 1. (a, b) Illustration of the PI and paper substrates showing the formation of LIG (PI-LIG, paper-LIG) films through laser irradiation. The corresponding cross-section and surface morphology SEM images are shown in (c, e) for PI-LIG and (d, f) paper-LIG samples, respectively, (g, h) illustration of the PI-Paper TENG with aluminium and LIG electrodes.

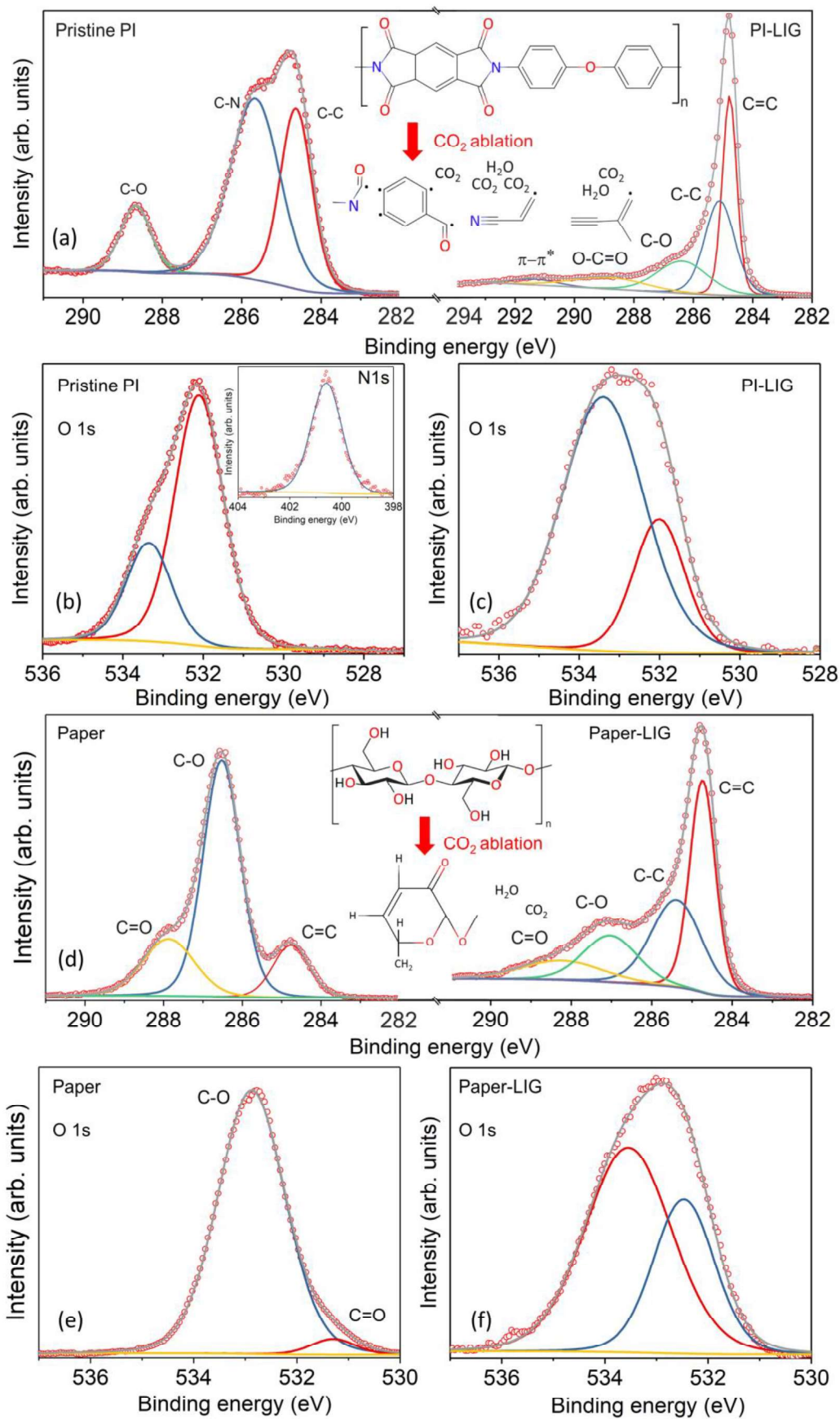


Fig. 2: (a) The variation of the C 1s XPS core-level spectra for pristine PI (left panel) which

changes significantly upon lasing (inset) confirming the formation of PI-LIG (right panel). The O 1s core-level spectra for (b) pristine PI and (c) PI-LIG samples. (c) The changes occurring in the C 1s core-level spectra when the pristine paper substrate (left panel) is converted to paper-LIG (right panel) upon CO₂ lasing process (inset). C 1s and O 1s spectra for paper substrate and paper-LIG are shown in (e, f) and (g, h), respectively.

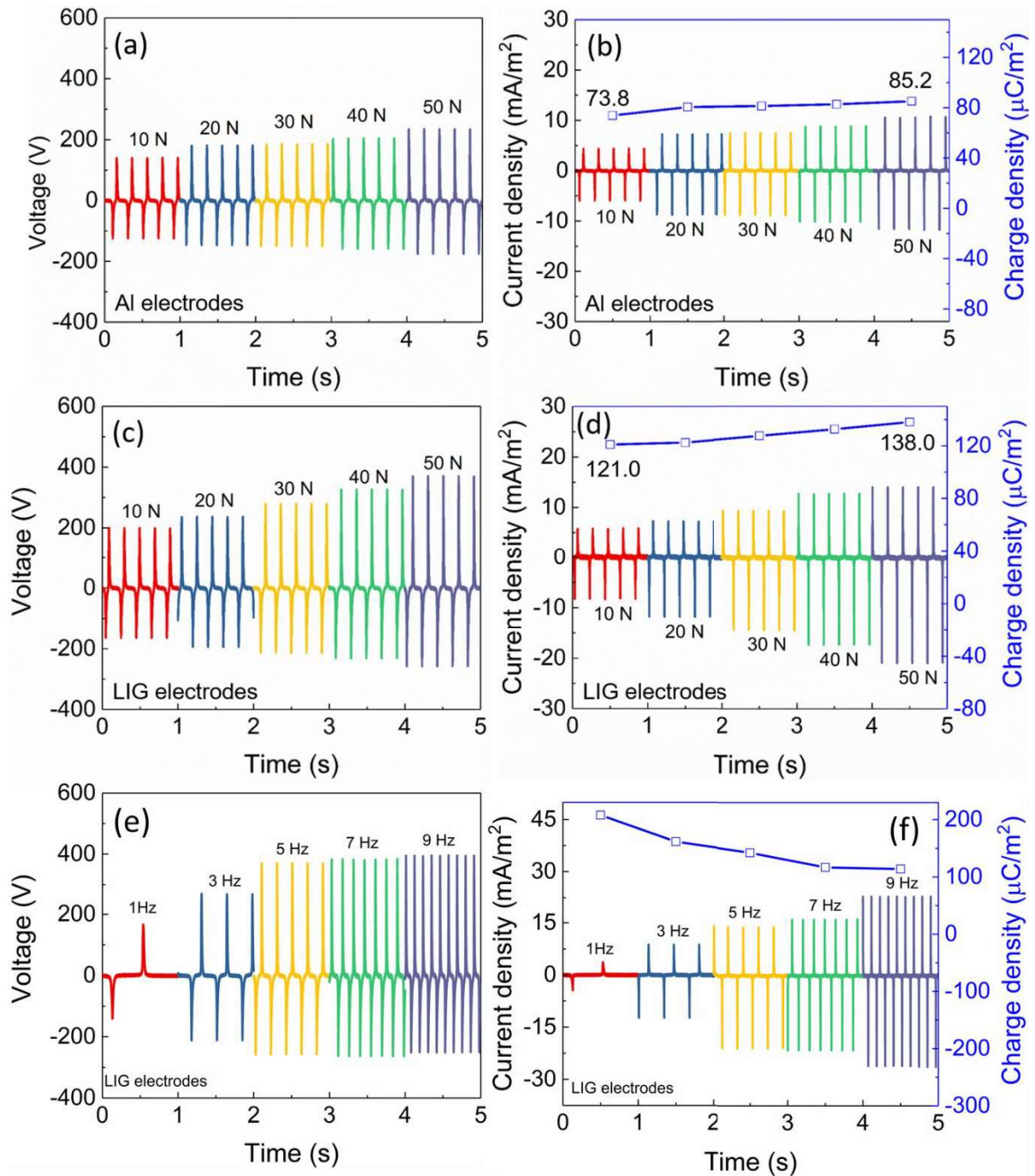


Fig. 3. Electrical measurement results of the paper/PI TENG with (a, b) aluminium electrodes and (c, d) LIG electrodes at various impact force ranging from 10 to 50 N. The corresponding charge density is obtained from the integral of the area under the curve for the current response. The PI-paper LIG TENGs were subjected to mechanical excitation at varying frequencies from 1-9 Hz with corresponding (e) voltage and (f) current density and charge density measurements, respectively.

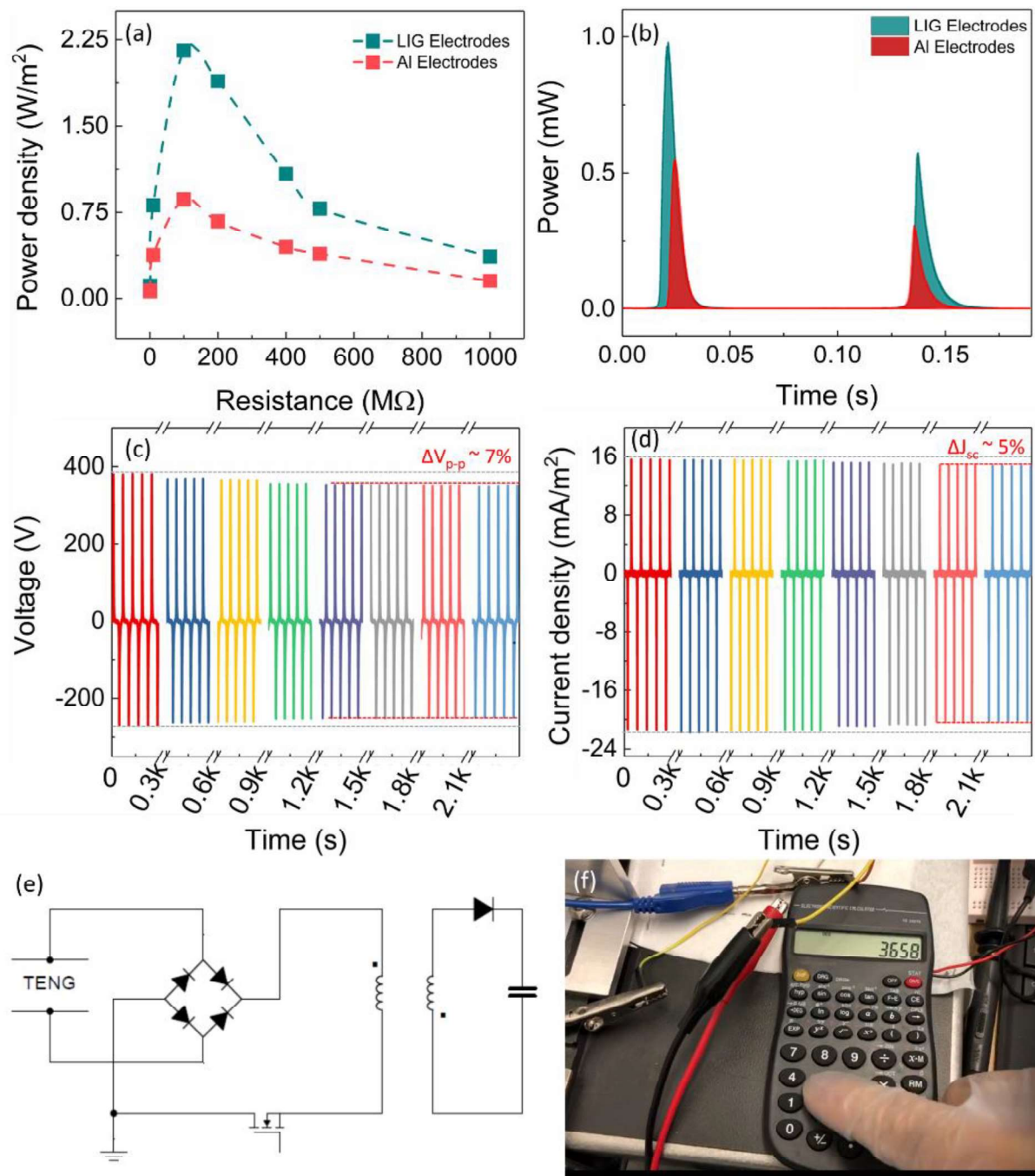


Fig. 4. (a) Power density values measured with variable load resistance for the paper/PI-LIG and paper/PI-Al TENGs, (b) the power output of a single energy generation cycle at the impedance matching condition (100 $\text{M}\Omega$). The paper/PI-LIG TENG shows consistent (c) voltage output with a $\Delta V_{p-p} \sim 7\%$, and (d) current density output (with $\Delta J_{sc} \sim 5\%$) behaviour for the test duration of 12,000 energy generation cycles at a fixed working frequency of 5 Hz, (e) schematic for the fly-back circuit, capable of efficiently storing the output of the paper/PI-LIG TENG, and (f) a scientific calculator being continuously powered by the fly-back circuit.

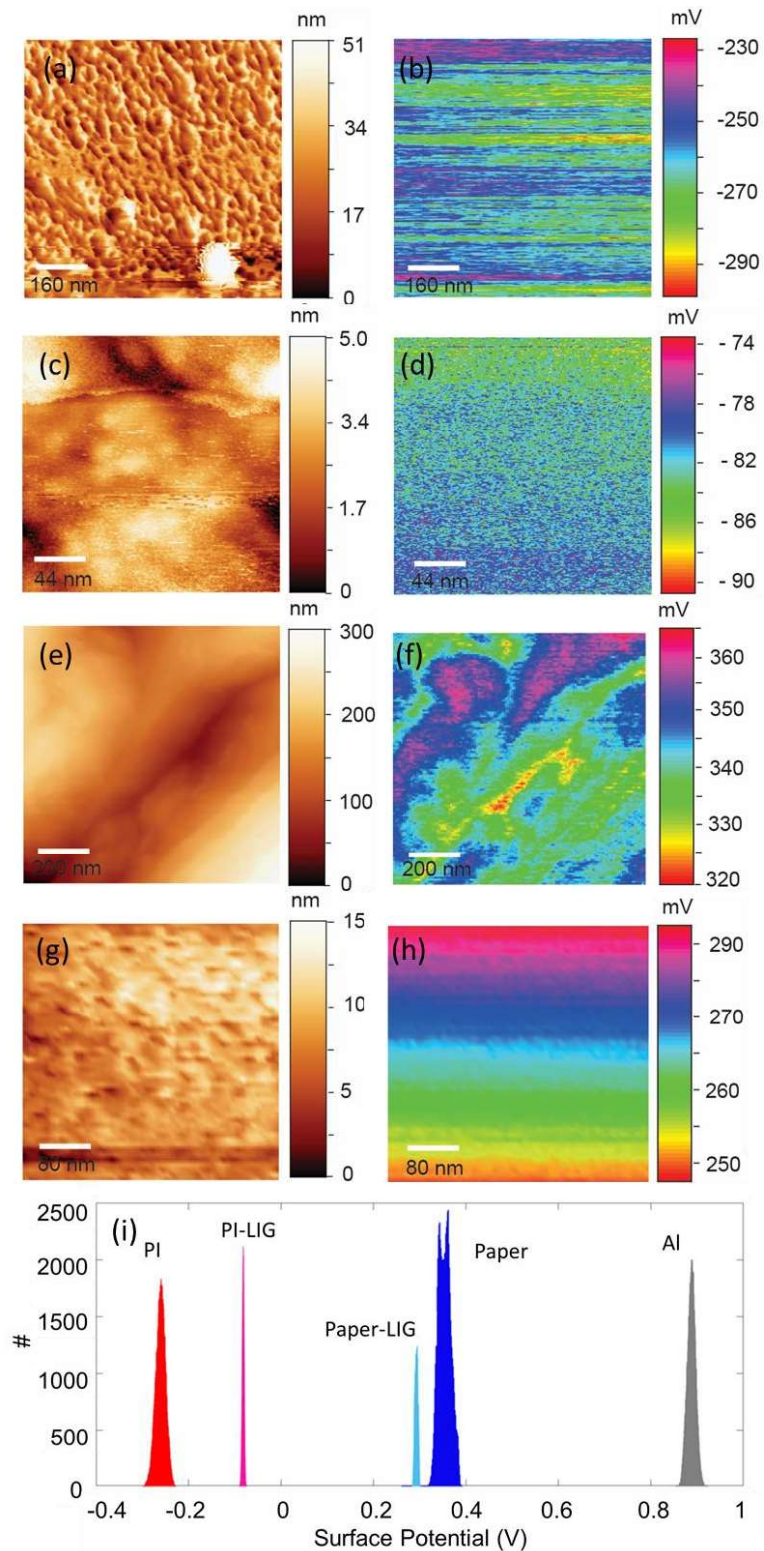


Fig. 5: The topography and surface potential maps for (a, b) pristine PI; (c, d) PI-LIG synthesised from pristine PI; (e, f) pristine cellulosic paper; (g, h) paper-LIG synthesised from paper treated with a fire-retardant, respectively; (i) the histogram of the distribution of the surface potentials of the pristine Al, PI, paper and the subsequent PI-LIG and paper-LIG substrates.

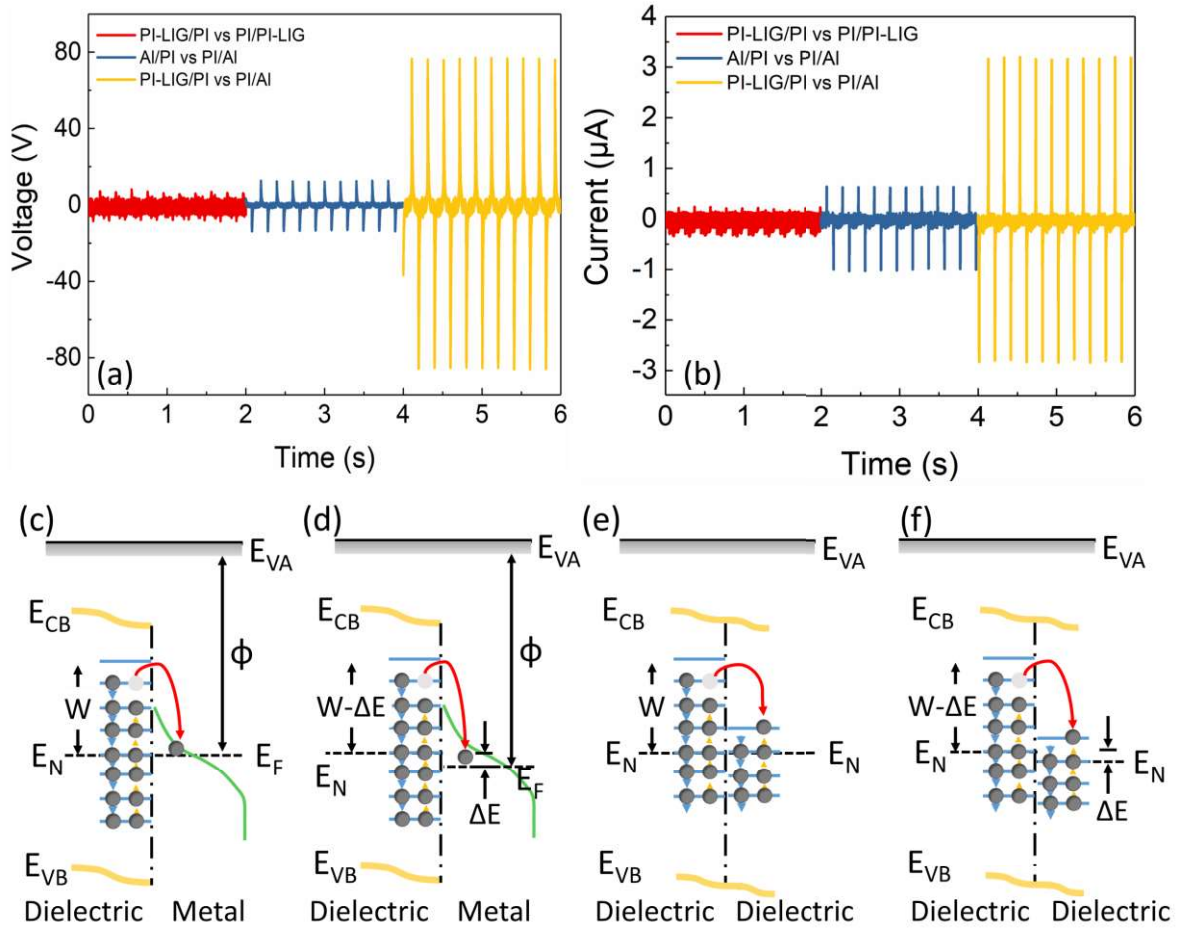


Fig. 6: Electrical measurement results (a) voltage output and (b) peak current values of the PI/PI TENG with various combination of electrodes at a fixed force of 50 N and 5 Hz frequency confirming the role of electrodes in dictating the electrical output from similar triboelectric materials. A depiction of surface state models for visualising of the regulation of potential barrier height of materials during the triboelectrification process is shown in (c-f). Charge transfer between a dielectric (with an initial negative charge) and conductor when the neutral level of surface states, E_N of the former is (c) as high as, (d) higher than of the latter. Charge transfer between dielectric A (with initial negative charges) and dielectric B when E_N of the former is (e) as high as, (f) higher than that of the latter. E_{VA} , vacuum level; E_{CB} , conduction band; E_{VB} , valence band; W , potential barrier; Φ , work function; and E_F , Fermi level.^[48]

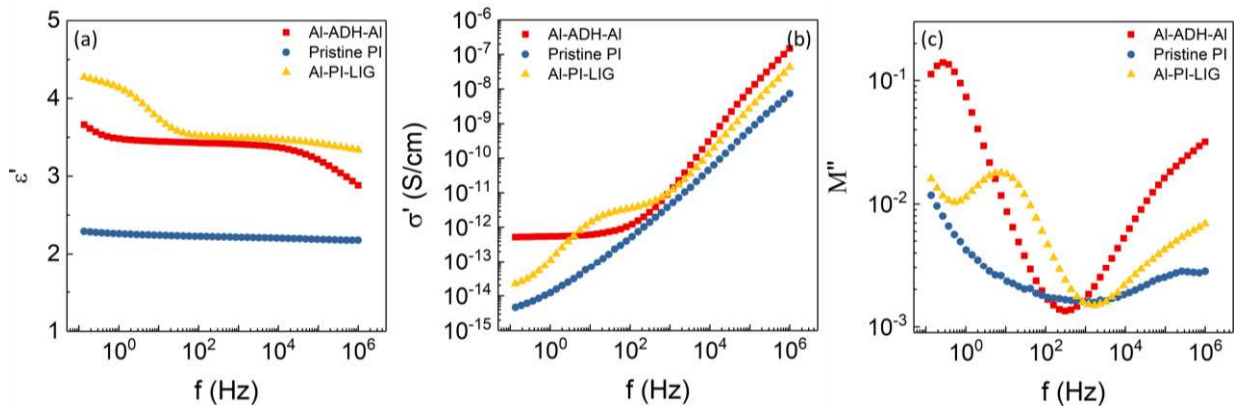


Fig. 7: (a) The variation of the dielectric permittivity ϵ' with the corresponding changes in the (b) AC electrical conductivity and (c) dependence of imaginary part of electric modulus as a function of frequency, for of the Al-adhesive-Al, pristine PI and Al-PI-(PI-LIG) combinations at room temperature.